

# High Common-Mode Voltage, Difference Amplifier

**AD629** 

#### **FEATURES**

Improved replacement for: INA117P and INA117KU ±270 V common-mode voltage range
Input protection to
 ±500 V common mode
 ±500 V differential mode
Wide power supply range (±2.5 V to ±18 V)
 ±10 V output swing on ±12 V supply
1 mA maximum power supply current

#### HIGH ACCURACY DC PERFORMANCE

3 ppm maximum gain nonlinearity (AD629B) 20 μV/°C maximum offset drift (AD629A) 10 μV/°C maximum offset drift (AD629B) 10 ppm/°C maximum gain drift

## **EXCELLENT AC SPECIFICATIONS**

77 dB minimum CMRR @ 500 Hz (AD629A) 86 dB minimum CMRR @ 500 Hz (AD629B) 500 kHz bandwidth

### **APPLICATIONS**

High voltage current sensing Battery cell voltage monitors Power supply current monitors Motor controls Isolation

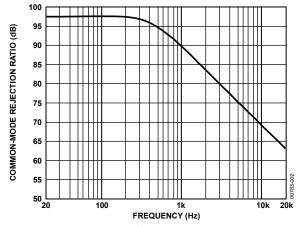
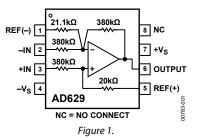


Figure 2. Common-Mode Rejection Ratio vs. Frequency

#### **FUNCTIONAL BLOCK DIAGRAM**



## **GENERAL DESCRIPTION**

The AD629 is a difference amplifier with a very high input, common-mode voltage range. It is a precision device that allows the user to accurately measure differential signals in the presence of high common-mode voltages up to  $\pm 270$  V.

The AD629 can replace costly isolation amplifiers in applications that do not require galvanic isolation. The device operates over a  $\pm 270$  V common-mode voltage range and has inputs that are protected from common-mode or differential mode transients up to  $\pm 500$  V.

The AD629 has low offset, low offset drift, low gain error drift, low common-mode rejection drift, and excellent CMRR over a wide frequency range.

The AD629 is available in low cost, 8-lead PDIP and 8-lead SOIC packages. For all packages and grades, performance is guaranteed over the industrial temperature range of  $-40^{\circ}$ C to  $+85^{\circ}$ C.

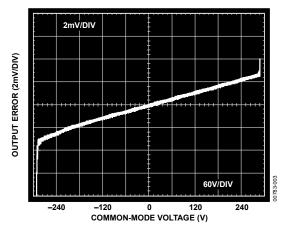


Figure 3. Error Voltage vs. Input Common-Mode Voltage

## **AD629**

## **TABLE OF CONTENTS**

reatures	1
Applications	1
Functional Block Diagram	1
General Description	1
Revision History	2
Specifications	3
Absolute Maximum Ratings	4
ESD Caution	4
Typical Performance Characteristics	5
Theory of Operation	9
Applications	10

Basic Connections
Single-Supply Operation
System-Level Decoupling and Grounding 10
Using a Large Sense Resistor11
Output Filtering11
Output Current and Buffering
A Gain of 19 Differential Amplifier12
Error Budget Analysis Example 1
Error Budget Analysis Example 2
Outline Dimensions
Ordering Guide

## **REVISION HISTORY**

10/99—Revision 0: Initial Version

## **SPECIFICATIONS**

 $T_A = 25$ °C,  $V_S = \pm 15$  V, unless otherwise noted.

Table 1.

			AD629/			AD6291		
Parameter	Condition	Min	Тур	Max	Min	Тур	Max	Unit
GAIN	$V_{OUT} = \pm 10 \text{ V}, R_L = 2 \text{ k}\Omega$							
Nominal Gain			1			1		V/V
Gain Error	n Error		0.01	0.05		0.01	0.03	%
Gain Nonlinearity			4	10		4	10	ppm
	$R_L = 10 \text{ k}\Omega$		1			1	3	ppm
Gain vs. Temperature	$T_A = T_{MIN}$ to $T_{MAX}$		3	10		3	10	ppm/°
OFFSET VOLTAGE								
Offset Voltage			0.2	1		0.1	0.5	mV
	$V_S = \pm 5 V$						1	mV
vs. Temperature	$T_A = T_{MIN}$ to $T_{MAX}$		6	20		3	10	μV/°C
vs. Supply (PSRR)	$V_S = \pm 5 \text{ V to } \pm 15 \text{ V}$	84	100		90	110		dB
INPUT								
Common-Mode Rejection Ratio	$V_{CM} = \pm 250 \text{ V dc}$	77	88		86	96		dB
	$T_A = T_{MIN}$ to $T_{MAX}$	73			82			dB
	$V_{CM} = 500 \text{ V p-p, dc to } 500 \text{ Hz}$	77			86			dB
	$V_{CM} = 500 \text{ V p-p, dc to 1 kHz}$		88			90		dB
Operating Voltage Range	Common mode			±270			±270	V
	Differential			±13			±13	V
Input Operating Impedance	Common mode		200			200		kΩ
	Differential		800			800		kΩ
OUTPUT								
Operating Voltage Range	$R_L = 10 \text{ k}\Omega$	±13			±13			V
, 3 3 3	$R_L = 2 k\Omega$	±12.5			±12.5			V
	$V_S = \pm 12 \text{ V}, R_L = 2 \text{ k}\Omega$	±10			±10			V
Output Short-Circuit Current			±25			±25		mA
Capacitive Load	Stable operation	1000			1000			рF
DYNAMIC RESPONSE	·							
Small Signal –3 dB Bandwidth			500			500		kHz
Slew Rate		1.7	2.1		1.7	2.1		V/µs
Full Power Bandwidth	V <sub>оит</sub> = 20 V p-p		28			28		kHz
Settling Time	0.01%, V <sub>OUT</sub> = 10 V step		15			15		μs
3	0.1%, V <sub>OUT</sub> = 10 V step		12			12		μs
	$0.01\%$ , $V_{CM} = 10 \text{ V step}$ , $V_{DIFF} = 0 \text{ V}$		5			5		μs
OUTPUT NOISE VOLTAGE								<u> </u>
0.01 Hz to 10 Hz			15			15		μV p-p
Spectral Density, ≥100 Hz <sup>1</sup>			550			550		nV/√H:
POWER SUPPLY								1
Operating Voltage Range		±2.5		±18	±2.5		±18	V
Quiescent Current	V <sub>OUT</sub> = 0 V		0.9	1		0.9	1	mA
2	T <sub>MIN</sub> to T <sub>MAX</sub>		1.2	•		1.2		mA
TEMPERATURE RANGE			<del>-</del>		1			1,
For Specified Performance	$T_A = T_{MIN}$ to $T_{MAX}$	-40		+85	-40		+85	°C

<sup>&</sup>lt;sup>1</sup> See Figure 19.

## **ABSOLUTE MAXIMUM RATINGS**

Table 2.

ı		
	Parameter	Rating
	Supply Voltage, V <sub>S</sub>	±18 V
	Internal Power Dissipation <sup>1</sup>	
	8-Lead PDIP (N)	See Figure 4
	8-Lead SOIC (R)	See Figure 4
	Input Voltage Range, Continuous	±300 V
	Common-Mode and Differential, 10 sec	±500 V
	Output Short-Circuit Duration	Indefinite
	Pin 1 and Pin 5	$-V_S - 0.3 \text{ V to } +V_S + 0.3 \text{ V}$
	Maximum Junction Temperature	150°C
	Operating Temperature Range	−55°C to +125°C
	Storage Temperature Range	−65°C to +150°C
	Lead Temperature (Soldering 60 sec)	300°C

 $<sup>^{1}</sup>$  Specification is for device in free air: 8-Lead PDIP,  $\theta_{JA}=100^{\circ}\text{C/W};$  8-Lead SOIC,  $\theta_{JA}=155^{\circ}\text{C/W}.$ 

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

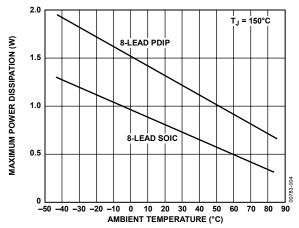


Figure 4. Maximum Power Dissipation vs. Temperature for SOIC and PDIP

## **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## TYPICAL PERFORMANCE CHARACTERISTICS

 $T_A = 25$ °C,  $V_S = \pm 15$  V, unless otherwise noted.

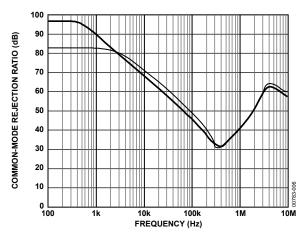


Figure 5. Common-Mode Rejection Ratio vs. Frequency

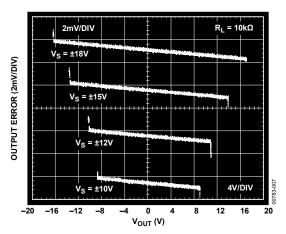


Figure 6. Typical Gain Error Normalized @  $V_{OUT} = 0$  V and Output Voltage Operating Range vs. Supply Voltage,  $R_L = 10$  k $\Omega$  (Curves Offset for Clarity)

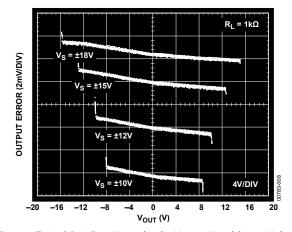


Figure 7. Typical Gain Error Normalized @  $V_{OUT}$  = 0 V and Output Voltage Operating Range vs. Supply Voltage,  $R_L$  = 1  $k\Omega$  (Curves Offset for Clarity)

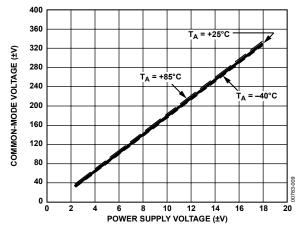


Figure 8. Common-Mode Operating Range vs. Power Supply Voltage

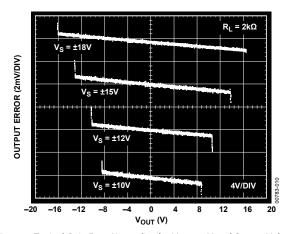


Figure 9. Typical Gain Error Normalized @  $V_{OUT} = 0$  V and Output Voltage Operating Range vs. Supply Voltage,  $R_L = 2 k\Omega$  (Curves Offset for Clarity)

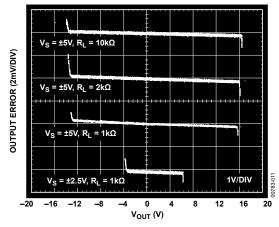


Figure 10. Typical Gain Error Normalized @ V<sub>OUT</sub> = 0 V and Output Voltage Operating Range vs. Supply Voltage (Curves Offset for Clarity)

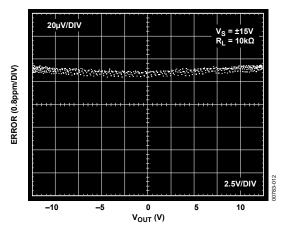


Figure 11. Gain Nonlinearity;  $V_S = \pm 15 \text{ V}$ ,  $R_L = 10 \text{ k}\Omega$ 

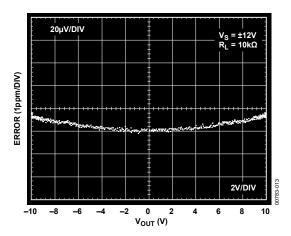


Figure 12. Gain Nonlinearity;  $V_S = \pm 12 \text{ V}$ ,  $R_L = 10 \text{ k}\Omega$ 

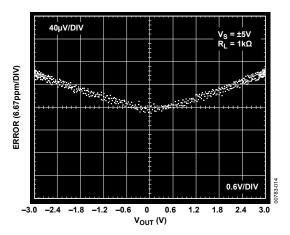


Figure 13. Gain Nonlinearity;  $V_S = \pm 5 V$ ,  $R_L = 1 k\Omega$ 

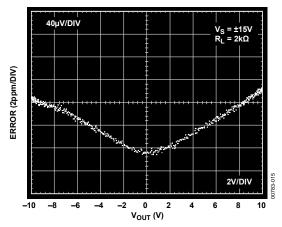


Figure 14. Gain Nonlinearity;  $V_S = \pm 15 \text{ V}$ ,  $R_L = 2k\Omega$ 

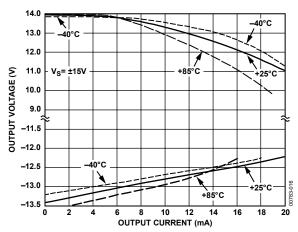


Figure 15. Output Voltage Operating Range vs. Output Current;  $V_S = \pm 15 \text{ V}$ 

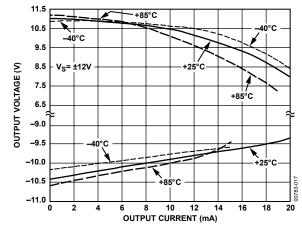


Figure 16. Output Voltage Operating Range vs. Output Current;  $V_S = \pm 12 \text{ V}$ 

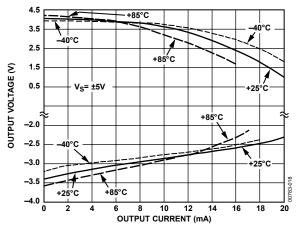


Figure 17. Output Voltage Operating Range vs. Output Current;  $V_S = \pm 5 V$ 

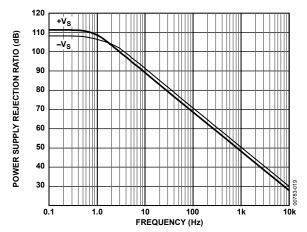


Figure 18. Power Supply Rejection Ratio vs. Frequency

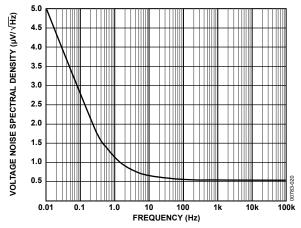


Figure 19. Voltage Noise Spectral Density vs. Frequency

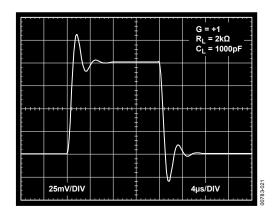


Figure 20. Small Signal Pulse Response

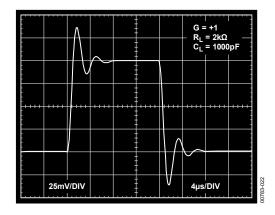


Figure 21. Small Signal Pulse Response

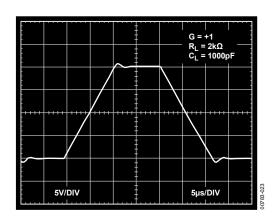


Figure 22. Large Signal Pulse Response

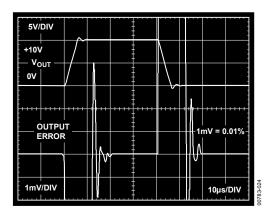


Figure 23. Settling Time to 0.01%, for 0 V to 10 V Output Step; G = -1,  $R_L = 2 k\Omega$ 

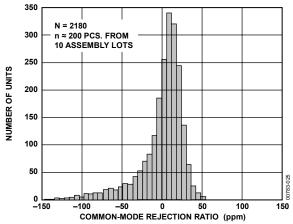


Figure 24. Typical Distribution of Common-Mode Rejection; Package Option N-8

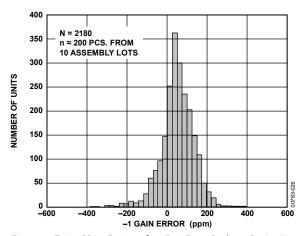


Figure 25. Typical Distribution of -1 Gain Error; Package Option N-8

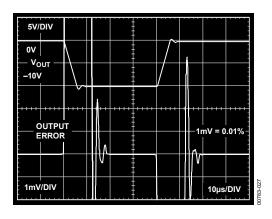


Figure 26. Settling Time to 0.01% for 0 V to -10 V Output Step; G = -1,  $R_L = 2k\Omega$ 

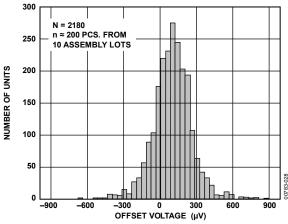


Figure 27. Typical Distribution of Offset Voltage; Package Option N-8

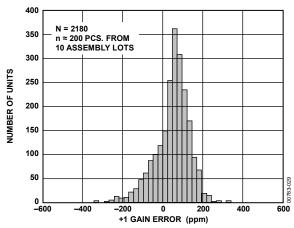


Figure 28. Typical Distribution of +1 Gain Error; Package Option N-8

## THEORY OF OPERATION

The AD629 is a unity gain, differential-to-single-ended amplifier (diff amp) that can reject extremely high common-mode signals (in excess of 270 V with 15 V supplies). It consists of an operational amplifier (op amp) and a resistor network.

To achieve high common-mode voltage range, an internal resistor divider (Pin 3 or Pin 5) attenuates the noninverting signal by a factor of 20. Other internal resistors (Pin 1, Pin 2, and the feedback resistor) restore the gain to provide a differential gain of unity. The complete transfer function equals

$$V_{OUT} = V (+IN) - V (-IN)$$

Laser wafer trimming provides resistor matching so that common-mode signals are rejected while differential input signals are amplified. To reduce output drift, the op amp uses super beta transistors in its input stage. The input offset current and its associated temperature coefficient contribute no appreciable output voltage offset or drift, which has the added benefit of reducing voltage noise because the corner where 1/f noise becomes dominant is below 5 Hz. To reduce the dependence of gain accuracy on the op amp, the open-loop voltage gain of the op amp exceeds 20 million, and the PSRR exceeds 140 dB.

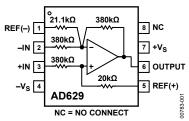


Figure 29. Functional Block Diagram

## **APPLICATIONS**

#### **BASIC CONNECTIONS**

Figure 30 shows the basic connections for operating the AD629 with a dual supply. A supply voltage of between  $\pm 3~V$  and  $\pm 18~V$  is applied between Pin 7 and Pin 4. Both supplies should be decoupled close to the pins using 0.1  $\mu F$  capacitors. Electrolytic capacitors of 10  $\mu F$ , also located close to the supply pins, may be required if low frequency noise is present on the power supply. While multiple amplifiers can be decoupled by a single set of 10  $\mu F$  capacitors, each in amp should have its own set of 0.1  $\mu F$  capacitors so that the decoupling point can be located right at the IC's power pins.

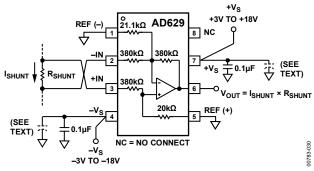


Figure 30. Basic Connections

The differential input signal, which typically results from a load current flowing through a small shunt resistor, is applied to Pin 2 and Pin 3 with the polarity shown to obtain a positive gain. The common-mode range on the differential input signal can range from -270 V to +270 V, and the maximum differential range is  $\pm 13$  V. When configured as shown in Figure 30, the device operates as a simple gain-of-1, differential-to-single-ended amplifier; the output voltage being the shunt resistance times the shunt current. The output is measured with respect to Pin 1 and Pin 5.

Pin 1 and Pin 5 (REF(-) and REF(+)) should be grounded for a gain of unity and should be connected to the same low impedance ground plane. Failure to do this results in degraded commonmode rejection. Pin 8 is a no connect pin and should be left open.

### SINGLE-SUPPLY OPERATION

Figure 31 shows the connections for operating the AD629 with a single supply. Because the output can swing to within only about 2 V of either rail, it is necessary to apply an offset to the output. This can be conveniently done by connecting REF(+) and REF(-) to a low impedance reference voltage (some ADCs provide this voltage as an output), which is capable of sinking current. Therefore, for a single supply of 10 V,  $V_{REF}$  may be set to 5 V for a bipolar input signal. This allows the output to swing  $\pm 3$  V around the central 5 V reference voltage. Alternatively, for unipolar input signals,  $V_{REF}$  can be set to about 2 V, allowing the output to swing from 2 V (for a 0 V input) to within 2 V of the positive rail.

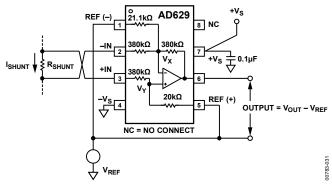


Figure 31. Operation with a Single Supply

Applying a reference voltage to REF(+) and REF(–) and operating on a single supply reduces the input common-mode range of the AD629. The new input common-mode range depends upon the voltage at the inverting and noninverting inputs of the internal operational amplifier, labeled  $V_X$  and  $V_Y$  in Figure 31. These nodes can swing to within 1 V of either rail. Therefore, for a (single) supply voltage of 10 V,  $V_X$  and  $V_Y$  can range between 1 V and 9 V. If  $V_{REF}$  is set to 5 V, the permissible common-mode range is +85 V to –75 V. The common-mode voltage ranges can be calculated by

$$V_{CM}(\pm) = 20 \ V_X/V_Y(\pm) - 19 \ V_{REF}$$

## SYSTEM-LEVEL DECOUPLING AND GROUNDING

The use of ground planes is recommended to minimize the impedance of ground returns (and therefore the size of dc errors). Figure 32 shows how to work with grounding in a mixed-signal environment, that is, with digital and analog signals present. To isolate low level analog signals from a noisy digital environment, many data acquisition components have separate analog and digital ground returns. All ground pins from mixed-signal components, such as ADCs, should return through a low impedance analog ground plane. Digital ground lines of mixed-signal converters should also be connected to the analog ground plane. Typically, analog and digital grounds should be separated; however, it is also a requirement to minimize the voltage difference between digital and analog grounds on a converter, to keep them as small as possible (typically <0.3 V). The increased noise, caused by the converter's digital return currents flowing through the analog ground plane, is typically negligible. Maximum isolation between analog and digital is achieved by connecting the ground planes back at the supplies. Note that Figure 32 suggests a "star" ground system for the analog circuitry, with all ground lines being connected, in this case, to the ADC's analog ground. However, when ground planes are used, it is sufficient to connect ground pins to the nearest point on the low impedance ground plane.

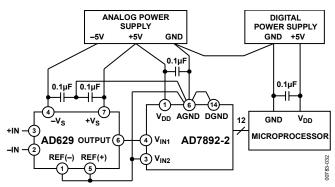


Figure 32. Optimal Grounding Practice for a Bipolar Supply Environment with Separate Analog and Digital Supplies

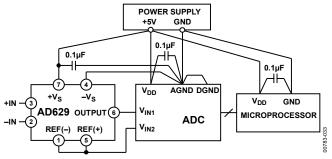


Figure 33. Optimal Ground Practice in a Single-Supply Environment

If there is only a single power supply available, it must be shared by both digital and analog circuitry. Figure 33 shows how to minimize interference between the digital and analog circuitry. In this example, the ADC's reference is used to drive Pin REF(+) and Pin REF(-). This means that the reference must be capable of sourcing and sinking a current equal to  $V_{\text{CM}}/200~\text{k}\Omega$ . As in the previous case, separate analog and digital ground planes should be used (reasonably thick traces can be used as an alternative to a digital ground plane). These ground planes should connect at the power supply's ground pin. Separate traces (or power planes) should run from the power supply to the supply pins of the digital and analog circuits. Ideally, each device should have its own power supply trace, but these can be shared by a number of devices, as long as a single trace is not used to route current to both digital and analog circuitry.

## **USING A LARGE SENSE RESISTOR**

Insertion of a large value shunt resistance across the input pins, Pin 2 and Pin 3, will imbalance the input resistor network, introducing a common-mode error. The magnitude of the error will depend on the common-mode voltage and the magnitude of  $R_{\text{SHUNT}}$ .

Table 3 shows some sample error voltages generated by a common-mode voltage of 200 V dc with shunt resistors from 20  $\Omega$  to 2000  $\Omega$ . Assuming that the shunt resistor is selected to use the full ±10 V output swing of the AD629, the error voltage becomes quite significant as R<sub>SHUNT</sub> increases.

Table 3. Error Resulting from Large Values of R<sub>SHUNT</sub> (Uncompensated Circuit)

	R <sub>s</sub> (Ω)	Error V <sub>OUT</sub> (V)	Error Indicated (mA)
,	20	0.01	0.5
	1000	0.498	0.498
	2000	1	0.5
		1	

To measure low current or current near zero in a high commonmode environment, an external resistor equal to the shunt resistor value can be added to the low impedance side of the shunt resistor, as shown in Figure 34.

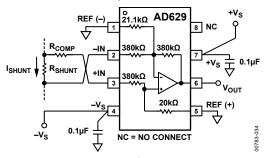


Figure 34. Compensating for Large Sense Resistors

## **OUTPUT FILTERING**

A simple 2-pole, low-pass Butterworth filter can be implemented using the OP177 after the AD629 to limit noise at the output, as shown in Figure 35. Table 4 gives recommended component values for various corner frequencies, along with the peak-to-peak output noise for each case.

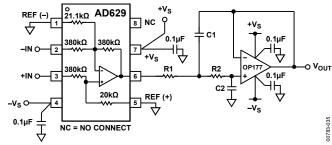


Figure 35. Filtering of Output Noise Using a 2-Pole Butterworth Filter

Table 4. Recommended Values for 2-Pole Butterworth Filter

Corner Frequency	R1	R2	C1	C2	Output Noise (p-p)
No Filter					3.2 mV
50 kHz	$2.94 \text{ k}\Omega \pm 1\%$	1.58 kΩ $\pm$ 1%	2.2 nF ± 10%	1 nF ± 10%	1 mV
5 kHz	$2.94 \text{ k}\Omega \pm 1\%$	1.58 kΩ $\pm$ 1%	22 nF ± 10%	10 nF ± 10%	0.32 mV
500 Hz	$2.94 \text{ k}\Omega \pm 1\%$	1.58 kΩ $\pm$ 1%	220 nF ± 10%	0.1 μF ± 10%	100 μV
50 Hz	$2.7 \text{ k}\Omega \pm 10\%$	1.5 kΩ $\pm$ 10%	2.2 μF ± 20%	1 μF ± 20%	32 μV

## **OUTPUT CURRENT AND BUFFERING**

The AD629 is designed to drive loads of 2 k $\Omega$  to within 2 V of the rails but can deliver higher output currents at lower output voltages (see Figure 15). If higher output current is required, the output of the AD629 should be buffered with a precision op amp, such as the OP113, as shown in Figure 36. This op amp can swing to within 1 V of either rail while driving a load as small as 600  $\Omega$ .

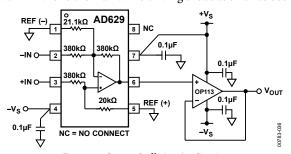


Figure 36. Output Buffering Application

### A GAIN OF 19 DIFFERENTIAL AMPLIFIER

While low level signals can be connected directly to the –IN and +IN inputs of the AD629, differential input signals can also be connected, as shown in Figure 37, to give a precise gain of 19. However, large common-mode voltages are no longer permissible. Cold junction compensation can be implemented using a temperature sensor, such as the AD590.

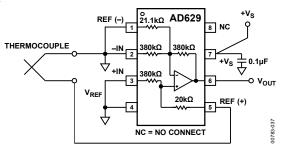


Figure 37. A Gain of 19 Thermocouple Amplifier

## **ERROR BUDGET ANALYSIS EXAMPLE 1**

In the dc application that follows, the 10 A output current from a device with a high common-mode voltage (such as a power supply or current-mode amplifier) is sensed across a 1  $\Omega$  shunt resistor (see Figure 38). The common-mode voltage is 200 V, and the resistor terminals are connected through a long pair of lead wires located in a high noise environment, for example, 50 Hz/60 Hz, 440 V ac power lines. The calculations in Table 5 assume an induced noise level of 1 V at 60 Hz on the leads, in addition to a full-scale dc differential voltage of 10 V. The error budget table quantifies the contribution of each error source. Note that the dominant error source in this example is due to the dc common-mode voltage.

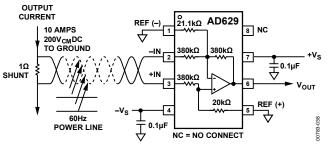


Figure 38. Error Budget Analysis Example 1:  $V_{IN}$  = 10 V Full-Scale,  $V_{CM}$  = 200 V DC,  $R_{SHUNT}$  = 1  $\Omega$ , 1 V p-p, 60 Hz Power-Line Interference

Table 5. AD629 vs. INA117 Error Budget Analysis Example 1 (V<sub>CM</sub> = 200 V dc)

			Error, ppm of FS	
Error Source	AD629	INA117	AD629	INA117
ACCURACY, T <sub>A</sub> = 25°C				
Initial Gain Error	$(0.0005 \times 10)/10 \text{ V} \times 10^6$	$(0.0005 \times 10)/10 \text{ V} \times 10^6$	500	500
Offset Voltage	$(0.001 \text{ V/}10 \text{ V}) \times 10^6$	$(0.002  \text{V}/10  \text{V}) \times 10^6$	100	200
DC CMR (Over Temperature)	$(224 \times 10^{-6} \times 200 \text{ V})/10 \text{ V} \times 10^{6}$	$(500 \times 10^{-6} \times 200 \text{ V})/10 \text{ V} \times 10^{6}$	4480	10,000
		Total Accuracy Error	5080	10,700
TEMPERATURE DRIFT (85°C)				
Gain	10 ppm/°C × 60°C	10 ppm/°C × 60°C	600	600
Offset Voltage	$(20 \mu\text{V/°C} \times 60^{\circ}\text{C}) \times 10^{6}/10 \text{V}$	$(40 \mu\text{V/°C} \times 60^{\circ}\text{C}) \times 10^{6}/10 \text{V}$	120	240
	•	Total Drift Error	720	840
RESOLUTION				
Noise, Typical, 0.01 Hz to 10 Hz, μV p-p	$15 \mu\text{V}/10 \text{V} \times 10^6$	$25 \mu\text{V}/10 \text{V} \times 10^6$	2	3
CMR, 60 Hz	$(141 \times 10^{-6} \times 1 \text{ V})/10 \text{ V} \times 10^{6}$	$(500 \times 10^{-6} \times 1 \text{ V})/10 \text{ V} \times 10^{6}$	14	50
Nonlinearity	$(10^{-5} \times 10 \text{ V})/10 \text{ V} \times 10^{6}$	$(10^{-5} \times 10 \text{ V})/10 \text{ V} \times 10^{6}$	10	10
		Total Resolution Error	26	63
		Total Error	5826	11,603

## **ERROR BUDGET ANALYSIS EXAMPLE 2**

This application is similar to the previous example except that the sensed load current is from an amplifier with an ac common-mode component of  $\pm 100~\rm V$  (frequency = 500 Hz) present on the shunt (see Figure 39). All other conditions are the same as before. Note that the same kind of power-line interference can happen as detailed in Example 1. However, the ac common-mode component of 200 V p-p coming from the shunt is much larger than the interference of 1 V p-p; therefore, this interference component can be neglected.

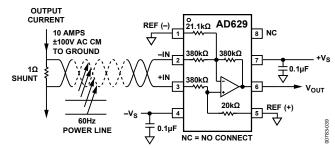
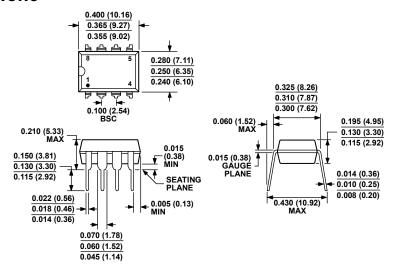


Figure 39. Error Budget Analysis Example 2:  $V_{IN}=10$  V Full-Scale,  $V_{CM}=\pm100$  V at 500 Hz,  $R_{SHUNT}=1$   $\Omega$ 

Table 6. AD629 vs. INA117 AC Error Budget Example 2 ( $V_{CM} = \pm 100 \text{ V} @ 500 \text{ Hz}$ )

			Error, ppm of FS	
Error Source	AD629	INA117	AD629	INA117
ACCURACY, T <sub>A</sub> = 25°C				
Initial Gain Error	$(0.0005 \times 10)/10 \text{ V} \times 10^6$	$(0.0005 \times 10)/10 \text{ V} \times 10^6$	500	500
Offset Voltage	$(0.001 \text{ V/}10 \text{ V}) \times 10^6$	$(0.002  \text{V}/10  \text{V}) \times 10^6$	100	200
	•	Total Accuracy Error	600	700
TEMPERATURE DRIFT (85°C)				
Gain	10 ppm/°C × 60°C	10 ppm/°C × 60°C	600	600
Offset Voltage	$(20 \mu\text{V/°C} \times 60^{\circ}\text{C}) \times 10^{6}/10 \text{V}$	$(40 \mu V/^{\circ}C \times 60^{\circ}C) \times 10^{6}/10 V$	120	240
	•	Total Drift Error	720	840
RESOLUTION				
Noise, Typical, 0.01 Hz to 10 Hz, μV p-p	$15 \mu\text{V}/10 \text{V} \times 10^6$	$25 \mu\text{V}/10 \text{V} \times 10^6$	2	3
CMR, 60 Hz	$(141 \times 10^{-6} \times 1 \text{ V})/10 \text{ V} \times 10^{6}$	$(500 \times 10^{-6} \times 1 \text{ V})/10 \text{ V} \times 10^{6}$	14	50
Nonlinearity	$(10^{-5} \times 10 \text{ V})/10 \text{ V} \times 10^{6}$	$(10^{-5} \times 10 \text{ V})/10 \text{ V} \times 10^{6}$	10	10
AC CMR @ 500 Hz	$(141 \times 10^{-6} \times 200 \text{ V})/10 \text{ V} \times 10^{6}$	$(500 \times 10^{-6} \times 200 \text{ V})/10 \text{ V} \times 10^{6}$	2820	10,000
	·	Total Resolution Error	2846	10,063
		Total Error	4166	11,603

## **OUTLINE DIMENSIONS**

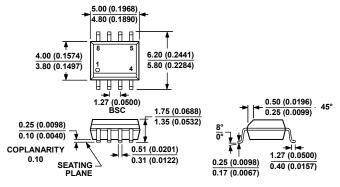


#### COMPLIANT TO JEDEC STANDARDS MS-001

CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 40. 8-Lead Plastic Dual In-Line Package [PDIP] (N-8)

Dimensions shown in inches and (millimeters)



## COMPLIANT TO JEDEC STANDARDS MS-012-AA

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 41. 8-Lead Standard Small Outline Package [SOIC\_N] (R-8)

Dimensions shown in millimeters and (inches)

## **ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option
AD629AN	-40°C to +85°C	8-Lead PDIP	N-8
AD629ANZ <sup>1</sup>	-40°C to +85°C	8-Lead PDIP	N-8
AD629AR	-40°C to +85°C	8-Lead SOIC_N	R-8
AD629AR-REEL	-40°C to +85°C	8-Lead SOIC_N	R-8
AD629AR-REEL7	-40°C to +85°C	8-Lead SOIC_N	R-8
AD629ARZ <sup>1</sup>	-40°C to +85°C	8-Lead SOIC_N	R-8
AD629ARZ-RL <sup>1</sup>	-40°C to +85°C	8-Lead SOIC_N, 13-Inch Tape and Reel, 2,500 pieces	R-8
AD629ARZ-R7 <sup>1</sup>	-40°C to +85°C	8-Lead SOIC_N, 7-Inch Tape and Reel, 1,000 pieces	R-8
AD629BN	-40°C to +85°C	8-Lead PDIP	N-8
AD629BNZ <sup>1</sup>	-40°C to +85°C	8-Lead PDIP	N-8
AD629BR	-40°C to +85°C	8-Lead SOIC_N	R-8
AD629BR-REEL	-40°C to +85°C	8-Lead SOIC_N, 13-Inch Tape and Reel, 2,500 pieces	R-8
AD629BR-REEL7	-40°C to +85°C	8-Lead SOIC_N, 7-Inch Tape and Reel, 1,000 pieces	R-8
AD629BRZ <sup>1</sup>	−40°C to +85°C	8-Lead SOIC_N	R-8
AD629BRZ-RL <sup>1</sup>	-40°C to +85°C	8-Lead SOIC_N, 13-Inch Tape and Reel, 2,500 pieces	R-8
AD629BRZ-R7 <sup>1</sup>	-40°C to +85°C	8-Lead SOIC_N, 7-Inch Tape and Reel, 1,000 pieces	R-8
AD629-EVAL		Evaluation Board	

 $<sup>^{1}</sup>$  Z = RoHS compliant part.

AD629			

NOTES